

## THESE HIGH-VOLTAGE, HIGH-CURRENT

Darlington arrays are comprised of seven silicon NPN darlington pairs on a common monolithic substrate. All units have open-collector outputs and integral diodes for inductive load transient suppression.

ULN2003 has a 2.7 k $\Omega$  series base resistor for each darlington pair, allowing operation directly with TTL or CMOS operating at a supply voltage of 5 V. These devices will handle numerous interface needs particularly those beyond the capabilities of standard logic buffers.

ULN2004 has a 10.5 k $\Omega$  series input resistor that permits operation directly from CMOS or PMOS outputs utilizing supply voltages of 6 to 15 V.

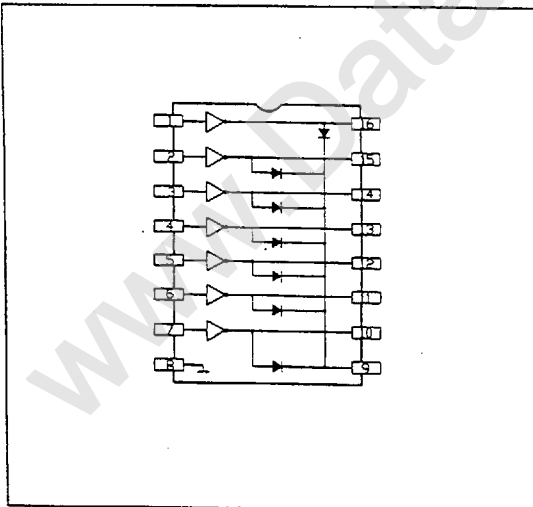
ULN2003/ULN2004 is the original high-voltage, high-current darlington array. The output transistors are capable of sinking 500 mA and will sustain at least 50 V in the off state. Output may be paralleled for higher load-current capability.

ULN2003/ULN2004 darlington arrays are furnished in a 16-Pin dual in-line plastic package. These can also be supplied in a hermetic dual in-line package for use in military and aerospace applications.

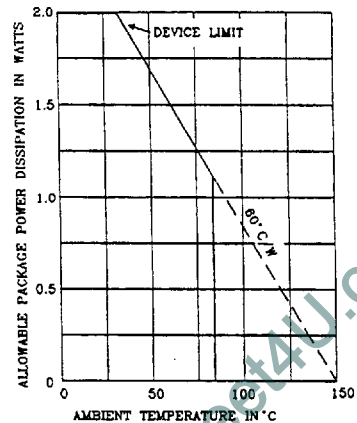
## DEVICE NUMBER DESIGNATION

VCE(MAX)	50V
IC(MAX)	500mA

Logic	Type Number
5V TTL, CMOS	ULN2003
6-15V CMOS, PMOS	ULN2004



## ALLOWABLE AVERAGE POWER DISSIPATION AS A FUNCTION OF AMBIENT TEMPERATURE



## ABSOLUTE MAXIMUM RATINGS

at +25 °C Free - Air Temperature  
( unless otherwise noted )

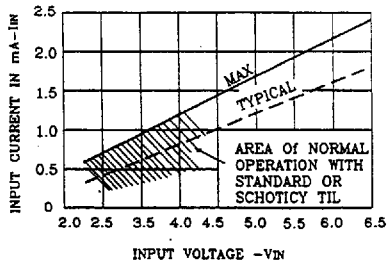
- Input Voltage,  $V_{IN}$  (ULN2003, ULN2004) . . . . . 30 V
- Continuous Input Current,  $I_{IN}$  . . . . . 25 mA
- Power Dissipation,  $P_D$  ( one Darlington pair ) . . . . . 1.0 W  
( total package ) . . . . . 2.0 W\*
- Operating Ambient Temperature Range,  $T_A$  . . . . . -20°C to +85°C
- Storage Temperature Range,  $T_S$  . . . . . -55°C to +150°C

\* Debate at the rate of 16.67 mW/°C above +25°C.

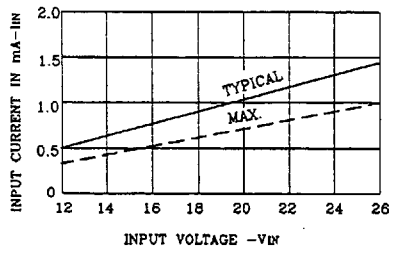
Under normal operating conditions, these devices will sustain 350 mA per output with  $V_{CE(STA)} = 1.6$  V at +70°C with a pulse width of 20 ms and a duty cycle of 34%.

## PARTIAL SCHEMATICS

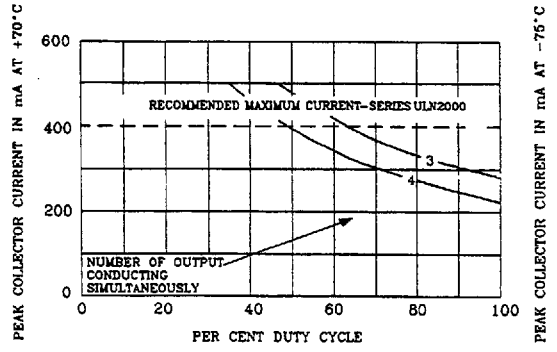
**Series ULN2003**  
(each driver)



**Series ULN2004**  
(each driver)



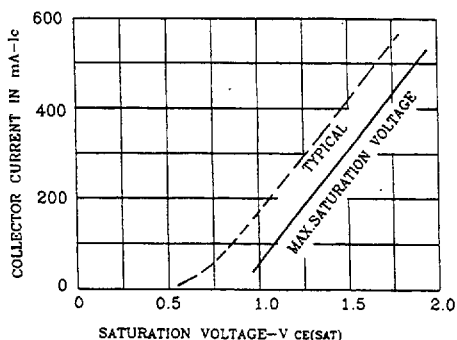
### PEAK COLLECTOR CURRENT AS A FUNCTION OF DUTY CYCLE



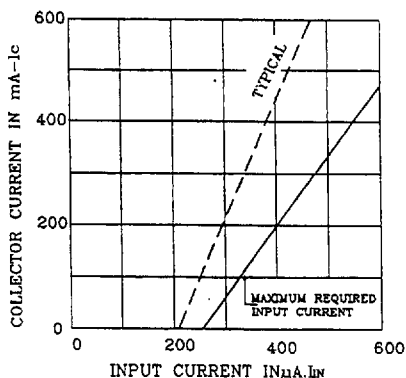
## ELECTRICAL CHARACTERISTICS AT +25°C ( unless otherwise noted )

Characteristic	Symbol	Test Fig.	Applicable Devices	Test Conditions	Limits					
					Min.	Typ.	Max.	Units		
Output Leakage Current	$I_{CEX}$	1A	All	$V_{CE}=50V, T_A=25^\circ C$	-	-	50	$\mu A$		
				$V_{CE}=50V, T_A=70^\circ C$	-	-	100	$\mu A$		
			ULN2004	$V_{CE}=50V, T_A=70^\circ C, V_{IN}=1.0V$	-	-	500	$\mu A$		
Collector - Emitter Saturation Voltage	$V_{CE(SAT)}$	2	All	$I_C=100mA, I_S=250\mu A$	-	0.9	1.1	V		
				$I_C=200mA, I_S=350\mu A$	-	1.1	1.3	V		
				$I_C=350mA, I_S=500\mu A$	-	1.3	1.6	V		
Input Current	$I_{IN(ON)}$	3	ULN2003	$V_{IN}=3.85V$	-	0.93	1.35	mA		
			ULN2004	$V_{IN}=5.0V$	-	0.35	0.5	mA		
			ULN2004	$V_{IN}=12V$	-	1.0	1.45	mA		
Input Voltage	$V_{IN(ON)}$	4	All	$I_C=500\mu A, T_A=70^\circ C$	50	65	-	$\mu A$		
				5	ULN2003	$V_{CE}=2.0V, I_C=200mA$	-	-	2.4	V
						$V_{CE}=2.0V, I_C=250mA$	-	-	2.7	V
					ULN2004	$V_{CE}=2.0V, I_C=300mA$	-	-	3.0	V
		$V_{CE}=2.0V, I_C=125mA$	-			-	5.0	V		
		5	ULN2003	$V_{CE}=2.0V, I_C=200mA$	-	-	6.0	V		
				$V_{CE}=2.0V, I_C=275mA$	-	-	7.0	V		
			ULN2004	$V_{CE}=2.0V, I_C=350mA$	-	-	8.0	V		
Input Capacitance	$C_{IN}$	-	All		-	15	25	pF		
Turn-On Delay	$t_{PLH}$	-	All	$0.5 E_{in}$ to $0.5 E_{out}$	-	0.25	1.0	$\mu S$		
Turn-Off Delay	$t_{PHL}$	-	All	$0.5 E_{in}$ to $0.5 E_{out}$	-	0.25	1.0	$\mu S$		
Clamp Diode Leakage Current	$I_R$	6	All	$V_R=50V, T_A=25^\circ C$	-	-	50	$\mu A$		
				$V_R=50V, T_A=70^\circ C$	-	-	100	$\mu A$		
Clamp Diode Forward Voltage	$V_F$	7	All	$I_F=350mA$	-	1.7	2.0	V		

**COLLECTOR CURRENT AS A FUNCTION OF SATURATION VOLTAGE**

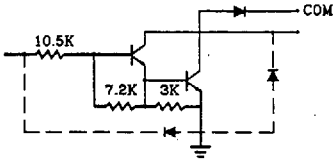


**COLLECTOR CURRENT AS A FUNCTION OF INPUT CURRENT**

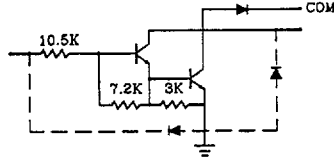


**INPUT CURRENT AS A FUNCTION OF INPUT VOLTAGE**

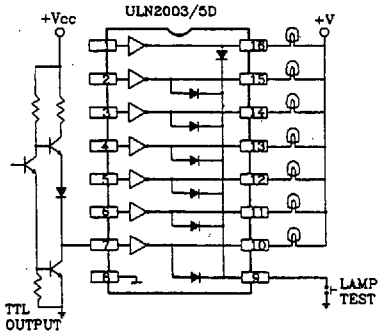
**SERIES ULN2003**



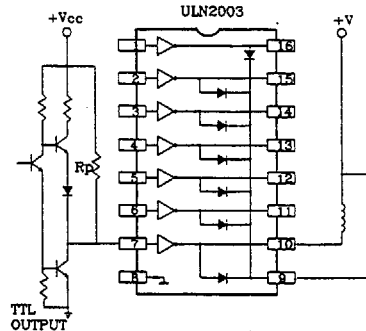
**SERIES ULN2004**



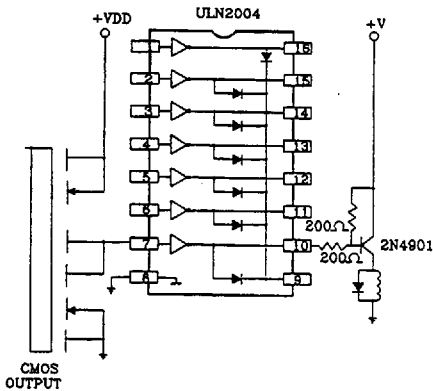
**TTL TO LOAD**



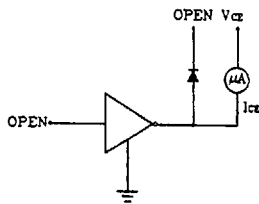
**USE OF PULL-UP RESISTORS TO INCREASE DRIVE CURRENT**



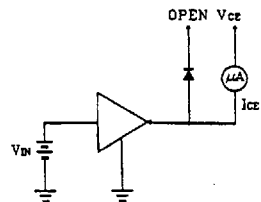
**BUFFER FOR HIGH-CURRENT LOAD**



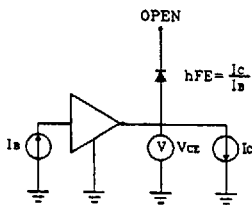
**TEST FIGURES**



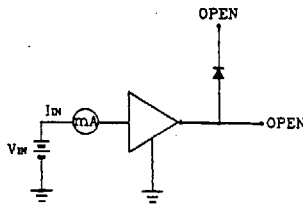
**FIGURE 1A**



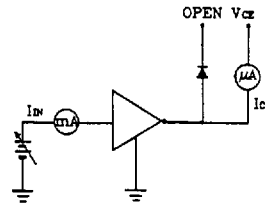
**FIGURE 1B**



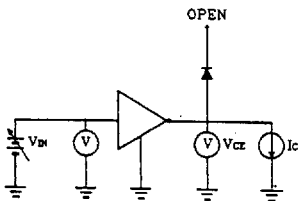
**FIGURE 2**



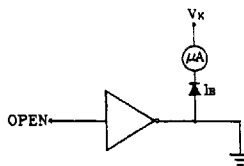
**FIGURE 3**



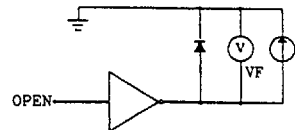
**FIGURE 4**



**FIGURE 5**



**FIGURE 6**



**FIGURE 7**